



DT1240-04LP

#### 4 CHANNELS LOW CAPACITANCE TVS DIODE ARRAY

## **Features & Applications**

- Clamping Voltage: 9V at 10A 100ns, TLP 9.4V at 5.5A 8µs/20µs
- IEC 61000-4-2 (ESD): Air ±16kV, Contact ±14kV
- IEC 61000-4-4 (EFT): Level 4
- IEC 61000-4-5 (Lightning): ±5.5A (8/20µs)
- 4 Channels of ESD Protection
- Low Channel Input Capacitance of 0.55pF Typical
- TLP Dynamic Resistance: 0.25Ω
- Typically Used for High Speed Ports such as USB 2.0, USB 3.0 DVI™, HDMI™2.0, Ethernet Port, IEEE, MDDI, PCI Express<sup>®</sup>, SATA/ eSATA
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative.

https://www.diodes.com/guality/product-definitions/

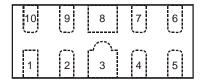
 An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DT1240-04LPQ</u>)

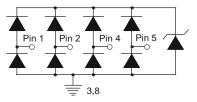
#### **Mechanical Data**

- Case: U-DFN2510-10
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiPdAu over Copper Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.038 grams (Approximate)

U-DFN2510-10 and U-DFN2510-10 (Type CJ)

Pin #	Description
1, 2, 4, 5	I/O
6, 7, 9, 10	No Connection
3, 8	Vss





Pin Description (Top View)

**Device Schematic** 

#### Ordering Information (Note 4)

Notes:

Part Number	Compliance	Marking Code	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DT1240-04LP-7	Standard	BC7	7	8	3,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

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#### **Marking Information**



BC7 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

BC7 YWX

BC7 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 1 = 2021) W = Week

(ex: a=Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key for YM

Year	2013		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	А		I	J	K	L	М	Ν	0	Р	R	S
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Date Code Key for YWX

Year	2013		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	3		1	2	3	4	5	6	7	8	9	0
Week	1-26				27	-52		53				
Code	A-Z					a	-Z		Z			
			n	ľ		ľ		'n			T	
Internal Code	Su	n	Mor	า	Tue	1	Ned	Thu		Fri		Sat
Code	Т		U		V		W	Х		Y		7



# Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Current, per IEC 61000-4-5	IPP	5.5	А	I/O to Vss, 8/20µs
Peak Pulse Power, per IEC 61000-4-5	PPP	60	W	I/O to Vss, 8/20µs
Operating Voltage (DC)	Vdc	6	V	I/O to Vss
ESD Protection – Contact Discharge, per IEC 61000-4-2	Vesd_contact	±14	kV	I/O to V <sub>SS</sub>
ESD Protection – Air Discharge, per IEC 61000-4-2	V <sub>ESD_AIR</sub>	±16	kV	I/O to V <sub>SS</sub>
Operating Temperature	TOP	-55 to +85	°C	—
Storage Temperature	Tstg	-55 to +150	°C	—

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation Typical (Note 5)	PD	350	mW
Thermal Resistance, Junction to Ambient Typical (Note 5)	Reja	360	°C/W

### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

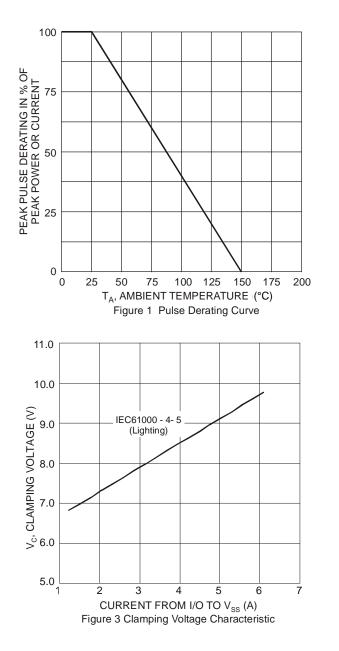
Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Reverse Working Voltage	VRWM		—	5.5	V	—
Reverse Current	IR	—	—	0.5	μA	$V_R = 5V$ , I/O to $V_{SS}$
Reverse Breakdown Voltage	VBR	6	_	_	V	I <sub>R</sub> = 1mA, I/O to Vss
Forward Clamping Voltage	VF	-1.0	-0.85	_	V	IF = -15mA, I/O to Vss
Holding Voltage	Vн	5.5	—	_	V	—
Reverse Clamping Voltage (Note 6)	Vc	_	9.4	11	V	IPP = 5.5A, I/O to Vss, 8/20µs
Trigger Voltage	V <sub>TRIG</sub>		_	9.5	V	—
ESD Clamping Voltage	Vesd	_	9	_	V	TLP, 10A, t <sub>P</sub> = 100ns, I/O to Vss
Dynamic Reverse Resistance	R <sub>DIF-R</sub>		0.25	_	Ω	TLP, 10A, $t_P$ = 100ns, I/O to V <sub>SS</sub>
Dynamic Forward Resistance	Rdif-f		0.25	_	Ω	TLP, 10A, t <sub>P</sub> = 100ns, V <sub>SS</sub> to I/O
Channel Input Capacitance (Note 7)	CI/O	_	0.55	0.65	pF	V <sub>I/O</sub> = 2.5V, V <sub>SS</sub> = 0V, f = 1MHz
Delta C <sub>I/O</sub>	CI/OMAX-CI/OMIN	—	0.04	_	pF	CI/OMAX-CI/OMIN

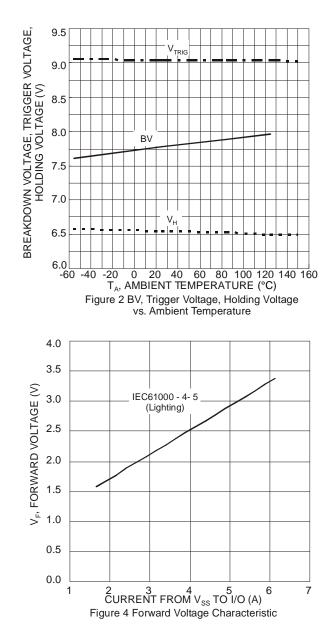
Notes: 5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.

6. Clamping voltage value is based on an  $8x20\mu s$  peak pulse current (Ipp) waveform.

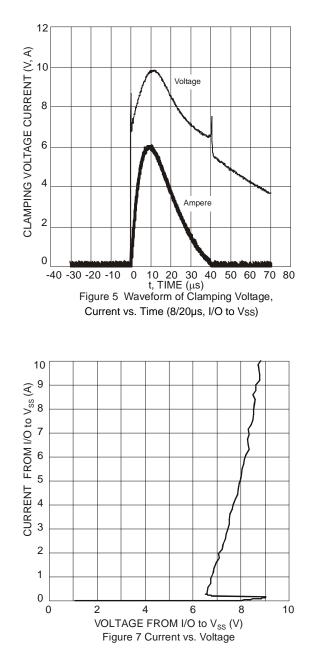
7. CI/01=CPIN1+CPIN10, CI/02=CPIN2+CPIN9, CI/03=CPIN4+CPIN7, CI/04=CPIN5+CPIN6

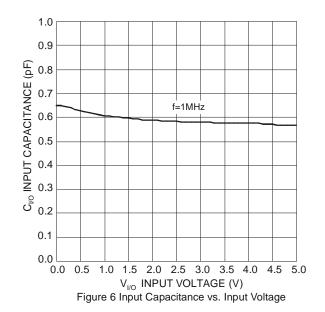








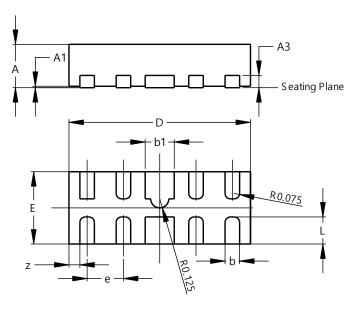






# Package Outline Dimensions

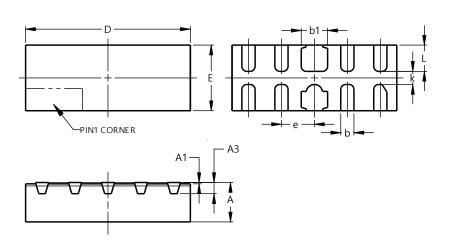
Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN2510-10
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U-DFN2510-10					
Dim	Min	Max	Тур		
Α	0.545	0.605	0.575		
A1	0.00	0.05	0.03		
A3	-	-	0.13		
b	0.15	0.25	0.20		
b1	0.35	0.45	0.40		
D	2.450	2.575	2.500		
е	-	-	0.50		
ш	0.950	1.075	1.000		
L	0.325	0.425	0.375		
z	-	-	0.150		
All D	imensi	ons in	mm		

U-DFN2510-10 (Type CJ)



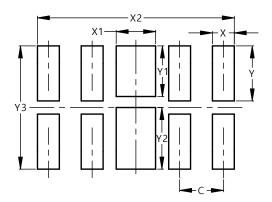
U-DFN2510-10 (Type CJ)					
Dim	Min	Max	Тур		
Α	0.545	0.605			
A1	0.00	0.05			
A3	0.	152RE	F		
b	0.150	0.250			
b1	0.350	0.450			
D	2.450	2.575			
E	0.950	1.075			
е			0.500		
Е	0.950	1.075	1.000		
L	0.350 0.450				
k	k 0.200REF				
All D	imensi	ons in	mm		



### Suggested Pad Layout

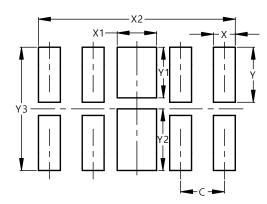
Please see http://www.diodes.com/package-outlines.html for the latest version.





Dimensions	Value (in mm)
С	0.500
Х	0.250
X1	0.450
X2	2.250
Y	0.625
Y1	0.575
Y2	0.700
Y3	1.400

#### U-DFN2510-10 (Type CJ)



Dimensions	Value (in mm)
С	0.500
Х	0.250
X1	0.450
X2	2.250
Y	0.625
Y1	0.575
Y2	0.700
Y3	1.400



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